

# High voltage discharge, High speed switching, Low Noise (-60V, -3A)

# 2SA2072

### Features

- 1) High speed switching. ( tf : Typ. : 20ns at Ic = -3A)
- 2) Low saturation voltage, typically.

(Typ. : -200mV at Ic = -2.0A, IB = -200mA)

- 3) Strong discharge power for inductive load and capacitance load.
- 4) Low Noise.
- 5) Complements the 2SC5825.

### Applications

High speed switching, Low noise

### ●Structure

PNP silicon epitaxial planar transistor

## Packaging specifications

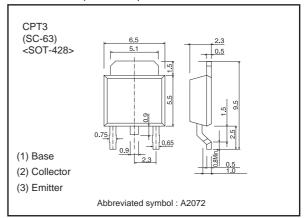
|         | Package                      | Taping |
|---------|------------------------------|--------|
| Туре    | Code                         | TL     |
|         | Basic ordering unit (pieces) | 2500   |
| 2SA2072 |                              | 0      |

# ●Absolute maximum ratings (Ta=25°C)

| Parameter                    |        | Symbol | Limits     | Unit |
|------------------------------|--------|--------|------------|------|
| Collector-base voltage       |        | Vсво   | -60        | V    |
| Collector-emitter voltage    |        | Vceo   | -60        | V    |
| Emitter-base voltage         |        | Vево   | -6         | V    |
| O. H. et e. e. e. et         | DC     | Ic     | -3         | А    |
| Collector current            | Pulsed | Icp *1 | -6         | А    |
| Power dissipation            |        | Pc     | 1.0 *2     | W    |
|                              |        | PC     | 10.0 *3    | W    |
| Junction temperature         |        | tj     | 150        | °C   |
| Range of storage temperature |        | tstg   | -55 to 150 | °C   |

<sup>\*1</sup> Pw=100ms

### ●Dimensions (Unit: mm)



<sup>\*2</sup> Ta=25°C

### ●Electrical characteristics (Ta=25°C)

| Parameter                            | Symbol         | Min. | Тур. | Max. | Unit | Condition  |  |
|--------------------------------------|----------------|------|------|------|------|--|--|
| Collector-emitter breakdown voltage  | BVceo          | -60  | -    | _    | V    | Ic=-1mA  |  |
| Collector-base breakdown voltage     | ВУсво          | -60  | _    | _    | V    | Ic=-100μA  |  |
| Emitter-base breakdown voltage       | ВVево          | -6   | _    | _    | V    | IE=-100μA  |  |
| Collector cut-off current            | Ісво           | _    | _    | -1.0 | μΑ   | VcB=-20V   |  |
| Emitter cut-off current              | ІЕВО           | _    | _    | -1.0 | μΑ   | V <sub>EB</sub> =-4V                               |  |
| Collector-emitter saturation voltage | VCE (sat)      | _    | -200 | -500 | mV   | Ic=-2A   |  |
|                                      |                |      |      |      |      | I <sub>B</sub> =-0.2A                              |  |
| DC current goin                      | hfe            | 120  | _    | 270  | -    | Vce=-2V  |  |
| DC current gain                      |                |      |      |      |      | Ic=-100mA  |  |
|                                      | *1             | _    | 180  | _    | MHz  | Vc=-10V  |  |
| Transistor frequency                 | f <sub>T</sub> |      |      |      |      | IE=100mA   |  |
|                                      |                |      |      |      |      | f=10MHz  |  |
|                                      |                | _    | 50   | _    | pF   | VcB=-10V   |  |
| Collector output capacitance         | Cob            |      |      |      |      | IE=0mA   |  |
|                                      |                |      |      |      |      | f=1MHz   |  |
| Turn-on time                         | ton *2         | _    | 20   | _    | ns   | Ic=-3A   |  |
| Storage time                         | tstg *2        | _    | 150  | -    | ns   | I <sub>B1</sub> = -300mA<br>I <sub>B2</sub> =300mA |  |
| Fall time                            | tf *2          | -    | 20   | -    | ns   | Vcc≒-25V   |  |

### ●hfe RANK

| Q       | _ |
|---------|---|
| 120–270 | _ |

### •Electrical characteristics curves

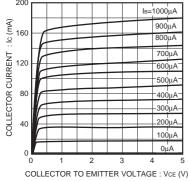


Fig.1 Typical output characteristics

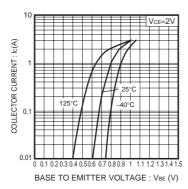


Fig.2 Grounded emitter propagation characteristics

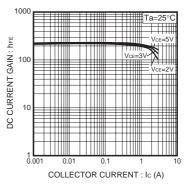


Fig.3 DC current gain vs.collector current (I)

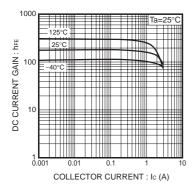


Fig.4 DC current gain vs.collector current (II)

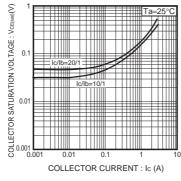


Fig.5 Collector-emitter saturation voltage vs.collector current (I)

2/3

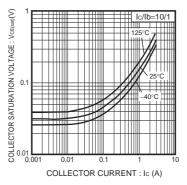


Fig.6 Collector-emitter saturation voltage vs.collector current ( II )

<sup>\*1</sup> Non repetitive pulse \*2 See switching characteristics measurement circuits

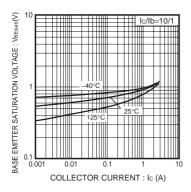


Fig.7 Base-emitter saturation voltage vs. collector current

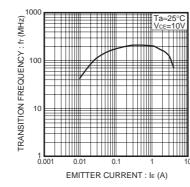


Fig.8 Transition frequency

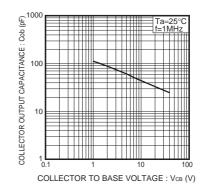


Fig.9 Collector output capacitance

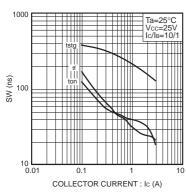
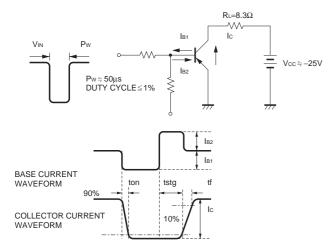


Fig.10 Switching Time

# •Switching characteristics measurement circuits



### **Notes**

No copying or reproduction of this document, in part or in whole, is permitted without the consent of ROHM Co.,Ltd.

The content specified herein is subject to change for improvement without notice.

The content specified herein is for the purpose of introducing ROHM's products (hereinafter "Products"). If you wish to use any such Product, please be sure to refer to the specifications, which can be obtained from ROHM upon request.

Examples of application circuits, circuit constants and any other information contained herein illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.

Great care was taken in ensuring the accuracy of the information specified in this document. However, should you incur any damage arising from any inaccuracy or misprint of such information, ROHM shall bear no responsibility for such damage.

The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM and other parties. ROHM shall bear no responsibility whatsoever for any dispute arising from the use of such technical information.

The Products specified in this document are intended to be used with general-use electronic equipment or devices (such as audio visual equipment, office-automation equipment, communication devices, electronic appliances and amusement devices).

The Products are not designed to be radiation tolerant.

While ROHM always makes efforts to enhance the quality and reliability of its Products, a Product may fail or malfunction for a variety of reasons.

Please be sure to implement in your equipment using the Products safety measures to guard against the possibility of physical injury, fire or any other damage caused in the event of the failure of any Product, such as derating, redundancy, fire control and fail-safe designs. ROHM shall bear no responsibility whatsoever for your use of any Product outside of the prescribed scope or not in accordance with the instruction manual.

The Products are not designed or manufactured to be used with any equipment, device or system which requires an extremely high level of reliability the failure or malfunction of which may result in a direct threat to human life or create a risk of human injury (such as a medical instrument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel-controller or other safety device). ROHM shall bear no responsibility in any way for use of any of the Products for the above special purposes. If a Product is intended to be used for any such special purpose, please contact a ROHM sales representative before purchasing.

If you intend to export or ship overseas any Product or technology specified herein that may be controlled under the Foreign Exchange and the Foreign Trade Law, you will be required to obtain a license or permit under the Law.

Thank you for your accessing to ROHM product informations.

More detail product informations and catalogs are available, please contact your nearest sales office.

**ROHM Customer Support System** 

THE AMERICAS / EUROPE / ASIA / JAPAN

www.rohm.com

Contact us : webmaster@rohm.co.jp

Copyright © 2009 ROHM Co.,Ltd.

ROHM Co., Ltd. 21 Saiin Mizosaki-cho, Ukyo-ku, Kyoto 615-8585, Japan

TEL:+81-75-311-2121 FAX:+81-75-315-0172

